

Low-frequency Transistor

[查询"2SB1198K"供应商](#)

(−80V, −0.5A)

2SB1198K

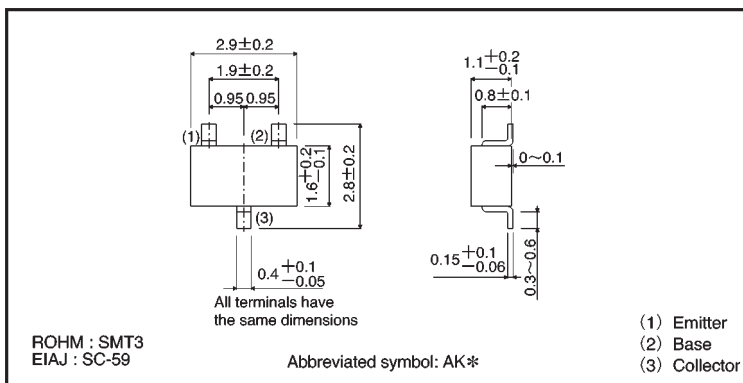
●Features

- 1) Low $V_{CE(sat)}$.
 $V_{CE(sat)} = -0.2V$ (Typ.)
($I_C / I_B = -0.5A / -50mA$)
- 2) High breakdown voltage.
 $BV_{CEO} = -80V$
- 3) Complements the 2SD1782K.

●Structure

Epitaxial planar type
PNP silicon transistor

●External dimensions (Unit:s mm)



●Absolute maximum ratings ($T_a = 25^\circ C$)

* Denotes h_{FE}

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	−80	V
Collector-emitter voltage	V_{CEO}	−80	V
Emitter-base voltage	V_{EBO}	−5	V
Collector current	I_C	−0.5	A
Collector power dissipation	P_C	0.2	W
Junction temperature	T_j	150	$^\circ C$
Storage temperature	T_{stg}	−55~+150	$^\circ C$

●Electrical characteristics ($T_a = 25^\circ C$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	−80	—	—	V	$I_C = -50 \mu A$
Collector-emitter breakdown voltage	BV_{CEO}	−80	—	—	V	$I_C = -2mA$
Emitter-base breakdown voltage	BV_{EBO}	−5	—	—	V	$I_E = -50 \mu A$
Collector cutoff current	I_{CBO}	—	—	−0.5	μA	$V_{CB} = -50V$
Emitter cutoff current	I_{EBO}	—	—	−0.5	μA	$V_{EB} = -4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	−0.2	−0.5	V	$I_C / I_B = -0.5A / -50mA$
DC current transfer ratio	h_{FE}	120	—	390	—	$V_{CE} = -3V, I_C = -0.1A$
Transition frequency	f_T	—	180	—	MHz	$V_{CE} = -10V, I_E = 50mA, f = 100MHz$
Output capacitance	C_{ob}	—	11	—	pF	$V_{CB} = -10V, I_E = 0A, f = 1MHz$

● Packaging specifications and h_{FE}

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Type	h_{FE}	Package	Taping
		Code	T146
		Basic ordering unit (pieces)	3000
2SB1198K	QR		○

 h_{FE} values are classified as follows :

Item	Q	R
h_{FE}	120~270	180~390

● Electrical characteristic curves

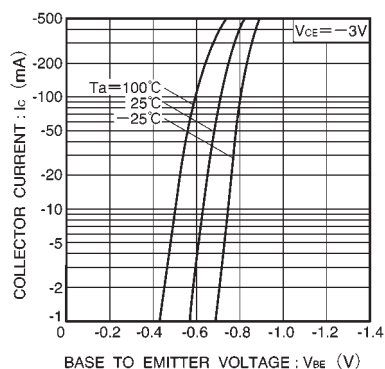


Fig.1 Grounded emitter propagation characteristics

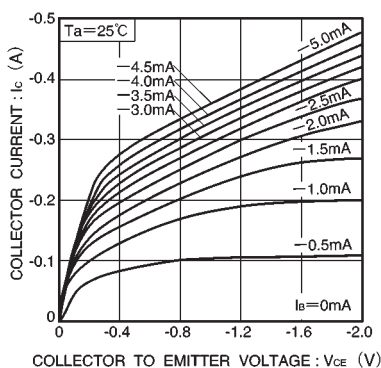


Fig.2 Grounded emitter output characteristics

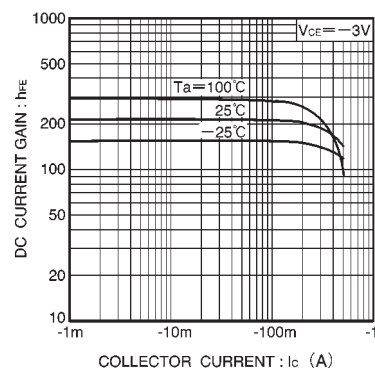


Fig.3 DC current gain vs. collector current

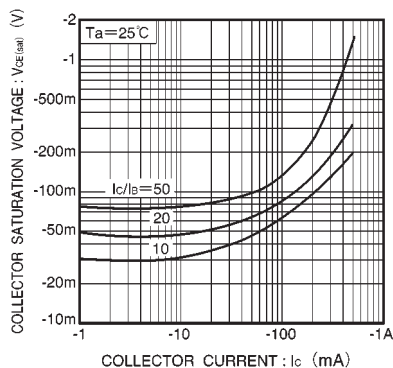


Fig.4 Collector-emitter saturation voltage vs. collector current (I)

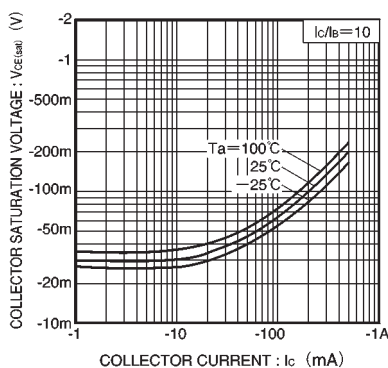


Fig.5 Collector-emitter saturation voltage vs. collector current (II)

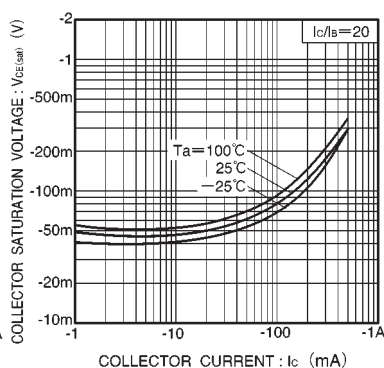


Fig.6 Collector-emitter saturation voltage vs. collector current (III)

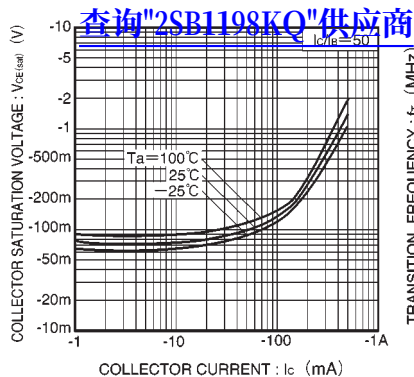


Fig.7 Collector-emitter saturation voltage vs. collector current (IV)

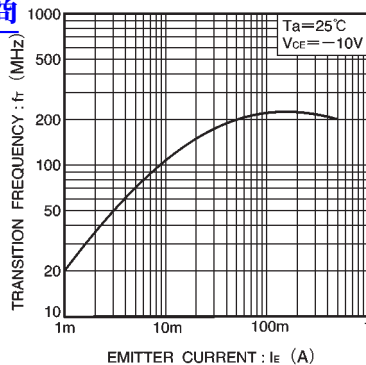


Fig.8 Gain bandwidth product vs. emitter current

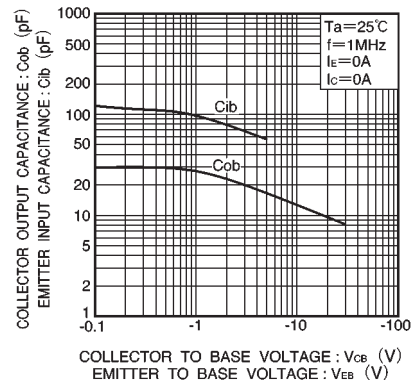


Fig.9 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage